Transport properties and electronic states of the therm oelectric oxide N aC o_2O_4

I. Terasaki*

Department of Applied Physics, W aseda University, Tokyo 169-8555, Japan Precursory Research for Embryonic Science and Technology, Japan Science Technology, Tokyo 108-0075, Japan

Physical properties of the therm collectric oxide $N \approx C_{02}O_4$ are brie y reviewed. The high therm collectric properties of this material are attributed to the substantially enhanced e ective mass, which comes from the large entropy of Co^{4+} in the low spin state. The large entropy conned in the CoO_2 block causes a spin-density-wave transition at 22 K upon Cu substitution for Co, which can be regarded as \order from disorder".

I. Introduction

Recently layered cobalt oxides have been extensively investigated as a promising candidate for a therm celectric m aterial. The therm oelectric m aterial is a m aterial that shows large therm opower (S), low resistivity () and low therm al conductivity () [1]. Thus far oxides have been regarded as unsuitable for them oelectric application because of their poor m obility, but som e years ago Terasakiet al. found that a single crystal of the layered cobalt oxide NaC 0204 exhibits high them oelectric perform ance [2]. Fujita et al. showed that the dimensionless qure of m erit $S^2 T = 0$ of a N aC $0,0_4$ single crystal exceeds unity at T = 1000 K [3]. O htakiet al. [4] m easured $S^2T =$ 0:8 at 1000 K even in the polycrystalline sam ples of N aC 0204. Thus this compound is quite promising for therm celectric power generation at high tem perature.

W e have proposed that the high them oelectric perform ance of the layered cobalt oxides cannot be explained by a conventional band picture based on the one-electron approxim ation, but is understood in terms of the strong electron-electron correlation e ects, sim ilarly to the case of heavy-ferm ion compounds. In fact the material dependence of the therm opower quite resembles that of $C \, eM_2 X_2 \, (M = Cu, Ni, Pd; X = Si, Ge)$ [5]. Here we brie y review the physical properties of NaCo₂O₄, and com pare them with those of the heavy-ferm ion com pounds. W e further show anom alous in purity e ects [6, 7], which are a prin e exam ple of \order from disorder" [8].

II. Physical Properties of N aC o₂O 4

In Fig.1 is schem atically shown the crystal structure of N aC o_2O_4 , where edge-shared distorted octahedra of oxygen ions form a two-dimensional triangular lattice. A cobalt ion is in the center of the distorted octahedra to form a two-dimensional triangular lattice, while a sodium ion is in a prism site between C oO_2 blocks. A n in portant feature in this structure is that sodium ions random ly occupy the regular site by 50%, and the sodium content changes from 50 to 75%. In this sense N aC o_2O_4 should be written as N a_x C O_2 (x= 0.5). N evertheless we will call it N aC o_2O_4 , because the best therm oelectric properties are realized near the 50% N a occupancy [4].

Figure 2 (a) shows the resistivity and the therm opower of a N aC $_{02}O_{4}$ single crystal along the a-axis (parallel to the C oO $_{2}$ block) direction. The magnitude of the resistivity is as low as 200 cm at 300 K, which corresponds to nearly the best conductivity among transition-metal oxides. The therm opower is 100 V/K at 300 K, which is as large as that of degenerate sem iconductors. As a result, the power factor S^{2} is as large as (or even larger than) S^{2} of the state-of-the-art therm oelectric material $B_{i2}Te_{3}$ [2].

Figure 2(b) shows the magnetic susceptibility and the speci c heat C of a polycrystalline sample of NaCo₂O₄ [7, 9]. The susceptibility is relatively large (4 10 ³ emu/Comolat 4 K), and weakly temperature dependent. We attribute the weakly temperature dependent susceptibility to a kind of spin uctuation, as is seen in the valence uctuation systems. In fact, Co-site substitution causes non-trivial change in the susceptibility. Nonmagnetic Zn substitution induces a Curie term, whereas magnetic Cu substitution decreases the magnitude of the susceptibility, which cannot be interpreted by the local spin picture [10].

The electron speci c heat coe cient is evaluated by the value of C=T as T ! 0. C=T approaches 35-50 m J/C o m o K², which is two orders of m agnitude larger than the value of conventional m etals. The large values of and clearly indicate that the density of states (and also

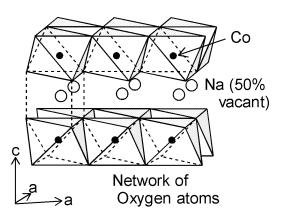
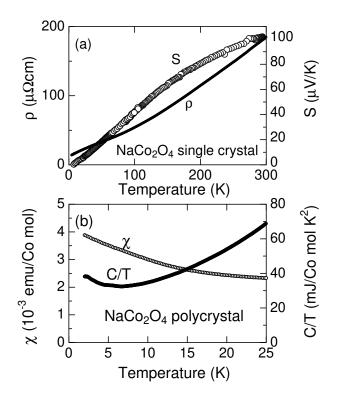


FIG.1: Crystal structure of N aC $o_2 O_4$.



 10^{4} CeCu₆ UBe₁₃-CeAla 10³ CeCu₂Si₂ UPt₃OO γ (mJ/mol K²) 10² 0 10¹ YbAl₂ C NàCo₂O₄ 10⁰ Ag \cap 10 10^{-4} 10⁻³ 10⁻² 10⁻¹ 10⁻⁵ χ (emu/mol)

FIG.3: Electron speci c heat \cos cient as a function of m agnetic susceptibility () for various correlated m etals.

FIG. 2: (a) Resistivity () and them opower (S) of a $N = C_2 O_4$ single crystal along the in-plane direction; (b) Susceptibility () and speci cheat (C) of $N = C_2 O_4$ polycrystals.

the e ective m ass) is substantially enhanced in N aC QO_4 . N ote that the band calculation by Singh [11] also predicts the large density of states, though it is di cult to explain the anom alous in purity e ects discussed later.

III. C om parison with C e-based interm etallics

The m icroscopic theory for the high therm oelectric perform ance of NaCo₂O₄ is still lacking, but we think that the following features are now established. (1) The m ixture of Co³⁺ and Co⁴⁺ in the low spin state can carry a large entropy of k_B log6, which gives a therm opower of 150 V/K in the high-temperature lim it [12]. (2) NaCo₂O₄ shows no structural, electric, and magnetic transitions from 2 to 1000 K. (3) From (1) (2), the large entropy cannot be released through phase transitions, and inevitably point to the conducting carriers to form a heavy-ferm ion"-like electron [7]. (4) A lthough an exact one-to-one correspondence is not realized, the calculated Ferm i surface of NaCo₂O₄ is made from two orbitals of di erent nature [11], just like C e 4f and sp bands in the C e-based interm etallics [5, 7].

In the heavy-ferm ion compounds, is proportional to the susceptibility , and = (the W ilson ratio) is independent of m aterials. In Fig.3, various 's are plotted as a function of , where the data for N aC o_2O_4 is just close to the data for the valence- uctuation compound C eP d [13]. We should note that CeP d₃ has nearly the same values of S (80 V/K at 300 K) and (150 m cm at 300 K). Unfortunately it has much higher therm al conductivity than NaCo₂O₄, which greatly reduces the therm oelectric perform ance.

A coording to the classical B oltzm ann theory, the diffusive term of the therm opower of a metal is understood as transport entropy per carrier, in plying that a large e ective mass can lead to a large therm opower. Figure 3 indicates that the e ective mass of N aC QO_4 is more than 10 times larger than the bare electron mass, which is in a quantitative agreement with the rectivity edge and the magnitude of the Hall e ect [13]. Considering a striking similarity to the heavy fermion compounds, we attribute the large mass of N aC o_2O_4 to the coherent state between the conduction carrier and the spin uctuation. Very recently Valla et al. have performed a photoem ission experiment for the layered cobalt oxides, and have successfully observed the coherent state at low tem peratures [14].

IV. Cu substitution e ects: Order from disorder

Figure 4(a) shows the speci c heat for the Cusubstituted sam pleN aCo_{1:8}Cu_{0:2}O₄ as a function oftem – perature, where the speci c heat jmp at 22 K is clearly seen [7]. The entropy change of the 22-K transition is as sm all as 77 m J/K m ol, corresponding to 0.01k_B per Co. A ctually only 5% of Co₃O₄ in purity exhibits a speci c heat jmp of the sam e order at 30 K. A phase transition accompanied by a sm allentropy change is an o -diagonal long range order, which induces a sm all entropy change of the order of N k_B T=E_F. This order is suppressed by

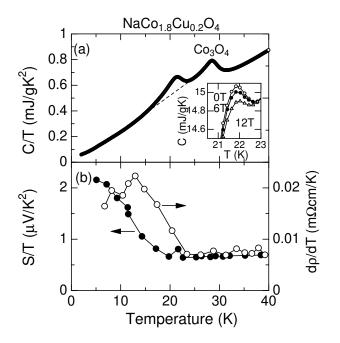


FIG. 4: (a) Speci c heat ∞ cient C (b) Temperature derivative of the resistivity (d =dT) and temperature ∞ cient of the therm opower S=T for the Cu-substituted N aC o_{1:8} Cu_{0:2}O₄. Inset: The speci c heat in magnetic elds.

external elds, as shown in the inset of Fig. 4 (a).

Figure 4(b) shows the T-linear term of the thermopower (S=T) and the temperature derivative of the resistivity d =dT. Their temperature dependences are quite similar to each other, where the magnitude increases up to almost twice below 22 K. This indicates that the D rude weight decreases by 50% at low tem peratures, im plying the existence of a (pseudo)gap. As an o -diagonal long-range order with a gapped state, one would think of charge density wave (CDW) or spin density wave (SDW). The calculated Ferm i surface of the a_{1g} band is hexagon-like [11], which is unstable against CDW or SDW form ation with the nesting vector along -K direction. W e think that the 22-K transition is the SDW -like, because CDW is insensitive to magnetic eld. A ctually we can nd m any sim ilarities between the 22-K transition and the SDW transition in Cr [15].

 $N = C \circ_2 O_4$ is very close to the instability for various phase transitions arising from the large entropy per site. The Cu substitution enhances the instability, and eventually causes the SDW —like transition at 22 K. This type

of transition is called \order from disorder" [8]. In other words, instabilities against various phases are competing or disordering in NaCo₂O₄, and any phase transitions are prohibited down to low temperatures. This does not mean that NaCo₂O₄ is far from the instability of phase transitions, but rather, is very susceptible to various transitions against various perturbations. In fact, Na_{1:5}Co₂O₄ exhibits a spin-glass behavior at 3 K [16] and a ferrom agnetic transition at 22 K [17], possibly owing to the structure instability of the phase, and (Bi,Pb)-Sr-Co-O shows a ferrom agnetic transition at 4 K due to the lattice m is t [18].

Let us qualitatively discuss why the SDW -like state is favored in NaCo₂ $_x$ Cu_xO₄. SDW and CDW are closely related to the nesting of the and the topology of the Ferm i surface, and occur when the correlation e ect is weak enough to hold one-electron picture based on the band calculation. We think that Cu suppresses the mass enhancement without signi cant change in the carrier concentration [7]. If so, the substituted Cu enhances the screening of the magnetic uctuation, which might recover the band picture to cause the CDW /SDW instability of the a_{1g} Ferm i surface.

V. Sum m ary

We have reviewed the anomalous properties of $N = 0_2 O_4$, which are promising for therm celectric applications. W e have explained the therm oelectric properties of N aC 020 4 in term softhe layered structure consisting of the strongly correlated $C \circ O_2$ layer. Carries in oxides are often coupled with the optical phonons, the spin degrees of freedom and the orbital degrees of freedom. These couplings induce exotic electronic states such as polarons, heavy ferm ions, spin liquids and orbital liquids. Furtherm ore, the geom etry and the dimensionality are easy to change in certain classes of oxides, where layered, ladder and chain structures can be controlled. Therefore I believe that m any functional m aterials including therm oelectric m aterials will still sleep unknown. I hope that N aC 020 4 is just the beginning, and that a therm celectric oxide of higher perform ance will appear in near future.

I would like to thank I.T sukada, T.M otohashiand H. Yam auchi for collaboration, and also thank S.K urihara and Y.T sunoda for fruitful discussion of spin density wave.

- [1] G.D.Mahan: Solid State Physics 51 (1998) 81.
- [2] I. Terasaki, Y. Sasago, and K. Uchinokura: Phys. Rev. B56 (1997) R12685.
- [3] K.Fujita, T.Mochida, and K.Nakamura: Jpn.J.Appl. Phys.40 (2001) 4644.
- [4] M. Ohtaki, Y. Nojiri and E. Maeda: Proc. of the 19th

InternationalConference on Therm celectrics (ICT2000), (Babrow, W ales, 2000) p.190.

- [5] I. Terasaki: M ater. Trans. 42 (2001) 951.
- [6] I. Terasaki, Y. Ishii, D. Tanaka, K. Takahata, and Y. Iguchi: Jpn.J.Appl.Phys.40 (2001) L65.
- [7] I. Terasaki, I. Tsuakda and Y. Iguchi: Phys. Rev. B, 65

- [8] A. M. Tsuvelik: \Q uantum eld theory in condensed m atter physics", (C am bridge University Press, 1995, C am bridge) p 174.
- [9] Y. Ando, Y. Hanaki, S. Ono, T. Murayama, K. Segawa, N. Miyamoto and S. Komiya: Phys. Rev. B 61 (2000) R 14956.
- [10] I. Terasaki: Proc. of International Conference on M ass and Charge Transport in Inorganic Materials (Techna Srl, 2000) p.1333
- [11] D.J.Singh: Phys. Rev. B 61 (2000) 13397.
- [12] W .Koshibae, K.T sutsuiand S.M aekawa: Phys. Rev.B 62 (2000) 6869.
- [13] I.Terasaki: Proc. of the 18th International Conference on

Therm celectrics (ICT 1999) (IEEE, P is cataway, 2000), p 569

- [14] T. Valla, P.D. Johnson, Z. Yusof, B. Wells, Q. Li, S.M. Loureiro, R.J. Cava, M. Mikami, Y. Mori, M. Yoshimura and T. Sasaki: Nature 417 (2002) 627.
- [15] E.Fawcett, H.L.Alberts, V.Yu.Galkin, D.R.Noakes, and J.V.Yakhm i: Rev.M od. Phys. 66 (1996) 25.
- [16] T. Takeuchi, M. M. atoba, T. A haren, and M. Itoh: Physica B 312-313 (2002) 719.
- [17] T.M otohashiet al.: subm itted to Phys. Rev. Lett.
- [18] I. Tsukada, T. Yam am oto, M. Takagi, T. Tsubone, S. Konno, and K. Uchinokura: J.Phys.Soc.Jpn.70 (2001) 834.